

MC10H643

Dual Supply ECL to TTL 1:8 Clock Driver

Description

The MC10H643 is a dual supply, low skew translating 1:8 clock driver. Devices in the ON Semiconductor H643 translator series utilize the PLCC-28 for optimal power pinning, signal flow through and electrical performance. The dual-supply H643 is similar to the H641, which is a single-supply 1:9 version of the same function.

The device features a 48 mA TTL output stage, with AC performance specified into a 50 pF load capacitance. A Latch is provided on-chip. When LEN is LOW (or left open, in which case it is pulled LOW by the internal pulldowns) the latch is transparent. A HIGH on the enable pin (\overline{EN}) forces all outputs LOW.

The MC10H643 is compatible with MECL 10H™ ECL logic levels.

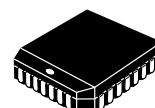
Features

- ECL/TTL Version of Popular ECLinPS™ E111
- Low Skew Within Device 0.5 ns
- Guaranteed Skew Spec Part-to-Part 1.0 ns
- Latch
- Differential Internal Design
- V_{BB} Output
- Dual Supply
- Reset/Enable
- Multiple TTL and ECL Power/Ground Pins
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



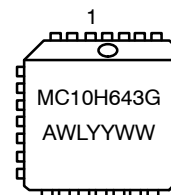
ON Semiconductor®

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PLCC-28
FN SUFFIX
CASE 776-02

MARKING DIAGRAM*



A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

*For additional marking information, refer to Application Note [AND8002/D](#).

ORDERING INFORMATION

Device	Package	Shipping
MC10H643FNG	PLCC-28 (Pb-Free)	37 Units/Tube

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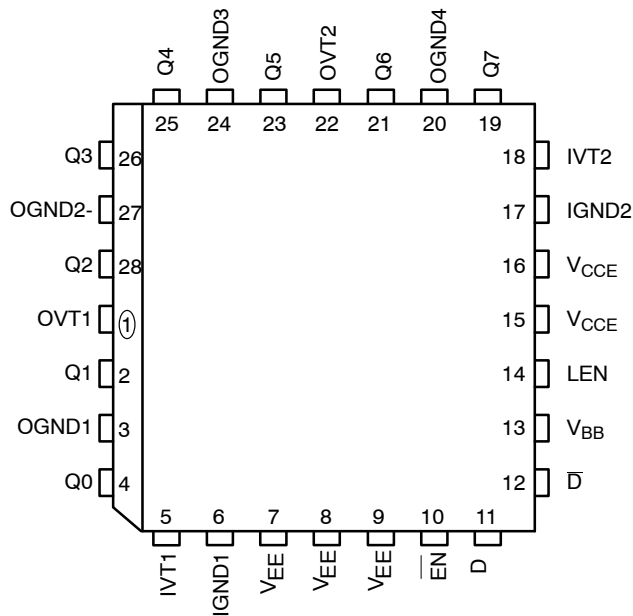


Figure 1. Pinout: PLCC-28
(Top View)

Table 1. PIN DESCRIPTION

PIN	FUNCTION
OGND	TTL Output Ground (0V)
OVT	TTL Output V_{CC} (+5.0V)
IGND	Internal TTL GND (0V)
IVT	Internal TTL V_{CC} (+5.0V)
V_{EE}	ECL V_{EE} (-5.2/-4.5V)
V_{CCE}	ECL Ground (0V)
D, \bar{D}	Signal Input (ECL)
V_{BB}	V_{BB} Reference Output
Q0 - Q7	Signal Outputs (TTL)
EN	Enable Input (ECL)
LEN	Latch Enable Input (ECL)

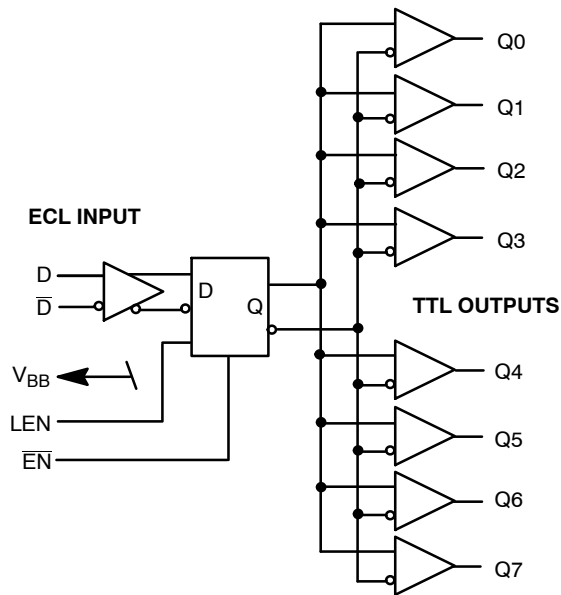


Figure 2. Logic Diagram

Table 2. TRUTH TABLE

D	LEN	EN	Q
L	L	L	L
H	L	L	H
X	H	L	Q_0
X	X	H	L

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Table 3. DC CHARACTERISTICS (IVT = OVT = 5.0 V \pm 5%; V_{EE} = -5.2 V \pm 5%)

Symbol	Characteristic		Condition	0°C		25°C		85°C		Unit
				Min	Max	Min	Max	Min	Max	
I _{EE}	Power Supply Current	ECL	V _{EE} Pins	–	42	–	42	–	42	mA
I _{CCL}		TTL	Total all OVT and IVT pins	–	106	–	106	–	106	mA
I _{CCH}				–	95	–	95	–	95	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Table 4. ECL DC CHARACTERISTICS (IVT = OVT = 5.0 V \pm 5%; V_{EE} = -5.2 V \pm 5%)

Symbol	Characteristic	0°C		25°C		85°C		Unit
		Min	Max	Min	Max	Min	Max	
I _{INH} I _{INL}	Input HIGH Current Input LOW Current	– 0.5	255 –	– 0.5	175 –	– 0.5	175 –	μA
V _{IH} V _{IL}	Input HIGH Voltage Input LOW Voltage	–1170 –1950	–840 –1480	–1130 –1950	–810 –1480	–1070 –1950	–735 –1450	mV
V _{BB}	Output Reference Voltage	–1380	–1270	–1350	–1250	–1310	–1190	mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Table 5. DC TTL CHARACTERISTICS (IVT = OVT = 5.0 V \pm 5%; V_{EE} = -5.2 V \pm 5%)

Symbol	Characteristic	Condition	0°C		25°C		85°C		Unit
			Min	Max	Min	Max	Min	Max	
V _{OH}	Output HIGH Voltage	I _{OH} = -3.0 mA I _{OH} = -15 mA	2.5 2.0	– –	2.5 2.0	– –	2.5 2.0	– –	V
V _{OL}	Output LOW Voltage	I _{OH} = 48 mA	–	0.5	–	0.5	–	0.5	V
I _{OS}	Output Short Circuit Current	V _{OUT} = 0 V	–100	–225	–100	–225	–100	–225	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

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Table 6. AC CHARACTERISTICS (IVT = OVT = 5.0 V \pm 5%; V_{EE} = -5.2 V \pm 10%; V_{CC}E = GND)

Symbol	Characteristic	Condition	0°C		25°C		85°C		Unit
			Min	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay to Output D LEN EN	CL = 50 pF	4.0 3.5 3.5	5.0 5.5 5.5	4.1 3.5 3.5	5.1 5.5 5.5	4.4 3.9 3.9	5.4 5.9 5.9	ns
t _{SK}	Within-Device Skew	(Note 1)	–	0.5	–	0.5		0.5	ns
t _w	Pulse Width Out HIGH or LOW @ f _{out} = 50MHz	CL = 50 pF (Note 2)	9.0	11.0	9.0	11.0	9.0	11.0	ns
t _s	Setup Time D		0.75	–	0.75	–	0.75	–	ns
t _h	Hold Time D		0.75	–	0.75	–	0.75	–	ns
t _{RR}	Recovery Time LEN EN		1.25 1.25	– –	1.25 1.25	– –	1.25 1.25	– –	ns
t _{pw}	Minimum Pulse Width LEN EN		1.5 1.5	– –	1.5 1.5	– –	1.5 1.5	– –	ns
t _r t _f	Rise / Fall Times 0.8 V – 2.0 V	CL = 50 pF	–	1.2	–	1.2	–	1.2	ns

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Within-Device skew defined as identical transitions on similar paths through a device.

2. Pulse width is defined relative to 1.5 V measurement points on the output waveform.

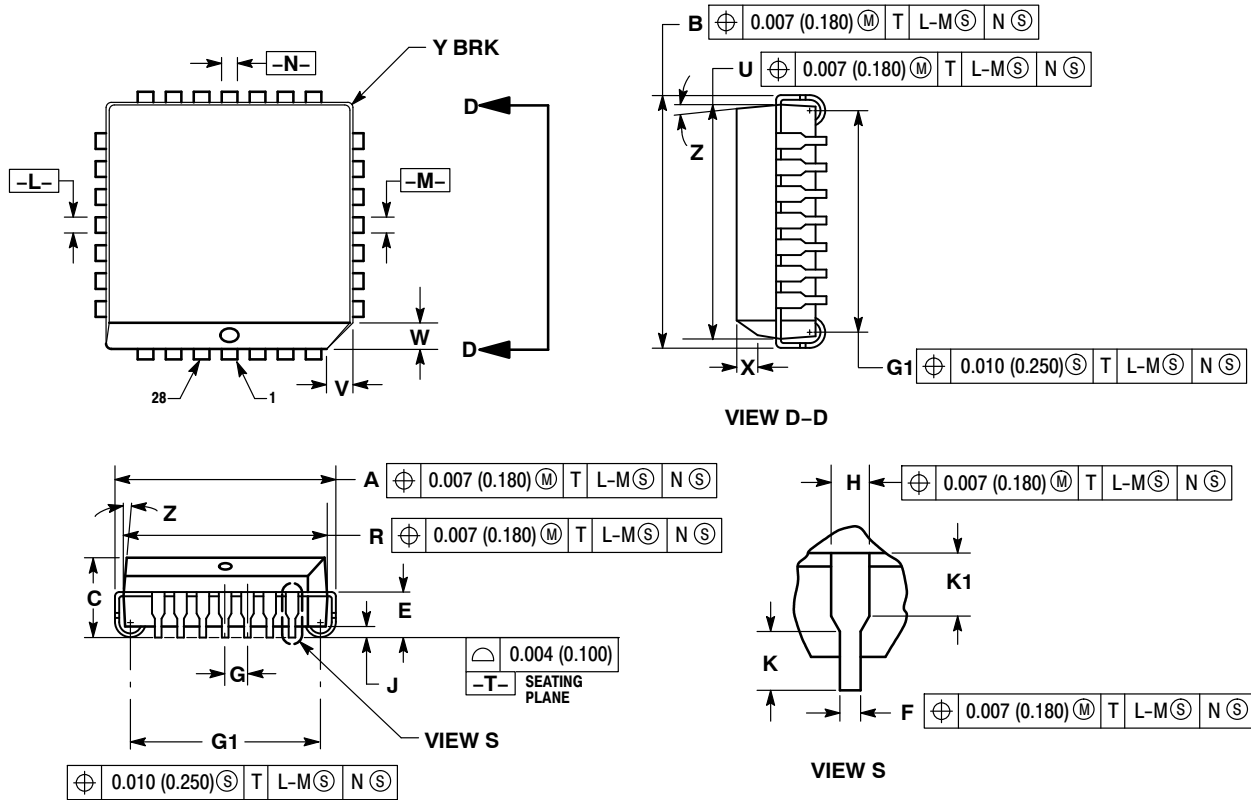
Resource Reference of Application Notes

- AN1405/D** – ECL Clock Distribution Techniques
- AN1406/D** – Designing with PECL (ECL at +5.0 V)
- AN1503/D** – ECLinPS™ I/O SPiCE Modeling Kit
- AN1504/D** – Metastability and the ECLinPS Family
- AN1568/D** – Interfacing Between LVDS and ECL
- AN1672/D** – The ECL Translator Guide
- AND8001/D** – Odd Number Counters Design
- AND8002/D** – Marking and Date Codes
- AND8020/D** – Termination of ECL Logic Devices
- AND8066/D** – Interfacing with ECLinPS
- AND8090/D** – AC Characteristics of ECL Devices

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PACKAGE DIMENSIONS

28 LEAD PLLC
CASE 776-02
ISSUE F




NOTES:

1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
5. CONTROLLING DIMENSION: INCH.
6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.485	0.495	12.32	12.57
B	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.021	0.33	0.53
G	0.050 BSC		1.27 BSC	
H	0.026	0.032	0.66	0.81
J	0.020	---	0.51	---
K	0.025	---	0.64	---
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y	---	0.020	---	0.50
Z	2°	10°	2°	10°
G1	0.410	0.430	10.42	10.92
K1	0.040	---	1.02	---

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